

Frequently asked questions and frequently encountered problems

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Outline

- Simulation flow can be divided into 3 main parts;
 - Configuration
 - Runtime
 - Analysis
- We will go through frequently asked questions and frequently encountered problems (and their solutions) for each part

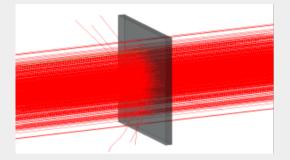


Configuration stage FAQ and FEP



Constructing geometry – things to consider

- Make sure that your incident particles actually hit the sensor(s) the way you want
- [VisualizationGeant4] is your friend here; opens the QtGui for Geant4
 - /run/beamOn is a handy command to see where particles from a source actually end up, compared to the sensor
 - This will also help figuring out the desired source directions
- Passive material: predefined shapes are "box", "cylinder", and "sphere", which is useful for material approximations.
 GDML file import is also available now, for more advanced structures
- When importing external electric fields: the collection electrode size definition is important!
 - When **not** doing transient simulations the *implant_size* in Allpix² should be slightly larger than in the imported field, to not lose charge due to final diffusion steps

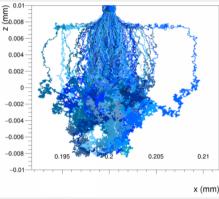


Example result from /run/beamOn 1000 in the QtGui command line



When to use which propagation and transfer?

- A propagation module propagates charges through the sensor
- [ProjectionPropagation] is **fast**, at the cost of precision. Can only be used with **linear** electric fields. Can be used for simple sensor approximations
- [GenericPropagation] is versatile and highly customisable. The best choice for precision, if transient pulses are not required. Can produce detailed linegraphs of charge movement
- [TransientPropagation] calculates the induced charge on neighbouring implants in each step. Creates current pulses. Requires weighting potential. Relatively slow, but gives a lot of information
 - Allpix² comes with a generate_potential tool, that can generate weighting potentials from model descriptions



Example linegraph from [GenericPropagation]



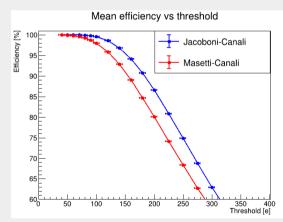
When to use which propagation and transfer?

- A transfer module transfers propagated charge to the readout electronics simulation stage (i.e. digitisation)
- [SimpleTransfer] makes a direct mapping of propagated charge to the nearest pixel
 - Can also be set to collect **only from the implant**
 - Important: set the max_depth_distance slightly larger than the collection implant depth in an imported field
- [InducedTransfer] **approximates the induced charge** on neighbouring pixels, by taking the difference in weighting potential between charge carrier start and end position. Requires weighting potential
 - Faster than using [TransientPropagation], and useful when a large fraction of particles get trapped (but still induce charge)
- [PulseTransfer] is required to transfer induced **pulses** created by [TransientPropagation]
 - Hence, use [PulseTransfer] if [TransientPropagation] is used
 - [PulseTransfer] will also create approximative pulses, if no pulse information is available (e.g. if [GenericPropagation] is used)



Propagation settings

- Propagation modules allow for different recombination models and mobility models
- Recombination models simulate charge carrier finite lifetime due to sensor material doping
 - The combined "srh_auger" model is recommended, as it applies to both low and high doping concentrations
- There are many mobility models available for silicon, and they basically split into doping-dependent and dopingindependent
 - Can have a significant impact on observables
 - The recommendation on what to use depends a lot on the simulated device and available information (electric field strength, doping concentration, temperature, ...)
 - The "extended Canali model" (*masetti_canali*) is a good choice when an electric field and a significant doping concentration are present
 - It is also possible to use a custom model



Example study comparing mobility models



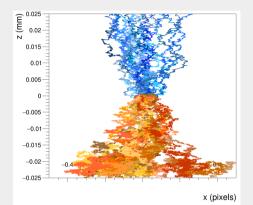
How to choose a specific particle source?

- Allpix² comes with several pre-defined particle sources
 - [DepositionReader]
 - [DepositionCosmics]
 - [DepositionPointCharge]
 - [DepositionGeant4]
- All useful for different things
 - [DepositionReader] takes in externally generated energy depositions into Allpix²
 - [DepositionCosmics] uses the Cosmic-ray shower generator (CRY) and Geant4 to generate and transport cosmic rays (see e.g. talk by Max)



Particle source: [DepositionPointCharge]

- Deposits user-defined charge in a single point or along a line
- Thus removes statistical fluctuations in deposition very useful for detailed sensor behaviour investigations!
- Two possible modes: Point and MIP
 - "Point" deposits charge in a single point in 3D space
 - "MIP" deposits charge along a straight line
- Deposits a given number of charges; total number for "point", and charge per length for "MIP"
- Three possible deposition models: "fixed", "spot", and "scan"
 - "Fixed" deposits charge in the same position each time
 - "Spot" smears the position over a Gaussian spot
 - "Scan" moves the deposition position homogeneously over a full pixel cell (in the middle of the pixel matrix)

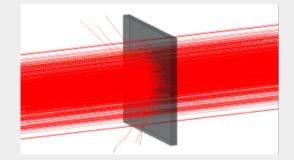


Single point deposition in pixel centre with subsequent drift of electrons and holes



Particle source: [DepositionGeant4]

- Generates Geant4 particles that can pass through the sensor and deposit energy, taking physical stochastic effects into account
 - Simulates particle decays, secondaries, Landau fluctuations, ...
- Predefined source shapes: beam, point, square, sphere
 - **Beam** is the default; can set many of the beam parameters
 - Particle flavour, beam direction, beam size and divergence, beam profile uniformity and energy, ...
 - Square and sphere: homogeneous emission over surface. Particle directions random by default, but can be set
 - Field inside sphere is isotropic; useful for space application studies
 - Particle flavours can also be radioactive elements; ⁵⁵Fe, ²⁴¹Am, ⁹⁰Sr, ⁶⁰Co, ¹³⁷Cs available, with simulated decays
- Can also do Geant4 macro for the General Particle Source
 - Can thus define **any** radioactive source, or any source shape
 - Also several different particles at once
 - Iron-55 photon example in backup slides. Link to GPS info here





Default and/or wrong units in configuration

- A common problem, with **big consequences**!
- The framework default units are:
 - Length: mm
 - Time: ns
 - Energy: MeV
 - Temperature: K
 - Charge: e (elementary charge)
 - Voltage: MV
 - Magnetic field: T
 - Angle: radian
- It is recommended to **always** specify the unit, to avoid mistakes
- The default unit might be unexpected (like MV), so **don't rely on it!**



Mesh conversion – importing field and doping

- When importing fields from e.g. TCAD, the *mesh_converter* tool can be used
- In the mesh_converter configuration file, make sure to:
 - Select the correct **region** in the source file to convert
 - Select the correct observable and its matching unit!
 - Electric field is typically in V/cm, and doping concentration in /cm/cm/cm
 - Getting them wrong can have a huge impact! Using V/cm for a doping concentration in cm⁻³ gives a final doping that is a factor of 10 000 too low
 - Newer Allpix² versions require units to be given, but **beware** of older versions and their default units
 - Select the **orientation** of the field
 - Tip: enabling output plots in [ElectricFieldReader] and [DopingProfileReader] in the Allpix² simulation is useful for examining the results
- When loading doping profiles into Allpix², be mindful of the **depth setting** (doping_depth)
 - If the setting doesn't match the profile size, the profile will get stretched or squished in the depth direction, to fit the Allpix² module setting
- For electric fields, the field outside of the imported mesh is set to 0. For doping profiles, the concentration is kept the same as the **last point within the depth setting**



Mesh conversion – how many divisions?

- The number of divisions relates to the **granularity** of the field in Allpix²
- The study below shows the effect of different settings on final observables, with an example field for a 20x20x10 μm^3 pixel

Mesh divisions	Mean cluster size	Resolution in x [µm]	Resolution in y [µm]	Efficiency [%]
<u>100</u> x <u>100</u> x100	2.696 ± 0.002	2.35 ± 0.01	2.37 ± 0.01	99.988 ± 0.002
<u>100</u> x <u>100</u> x50	2.817 ± 0.003	2.28 ± 0.01	2.29 ± 0.01	99.993 ± 0.002
<u>100</u> x <u>100</u> x10	2.693 ± 0.003	2.36± 0.01	2.38 ± 0.01	99.986 ± 0.002
300x300x <u>100</u>	2.696 ± 0.002	2.35 ± 0.01	2.37 ± 0.01	99.988 ± 0.002
100x100x <u>100</u>	2.696 ± 0.002	2.35 ± 0.01	2.37 ± 0.01	99.988 ± 0.002
50x50x <u>100</u>	2.695 ± 0.003	2.35 ± 0.01	2.37 ± 0.01	99.987 ± 0.002
20x20x <u>100</u>	2.930 ± 0.003	2.22 ± 0.01	2.24 ± 0.01	99.993 ± 0.002

- Changes in z (depth) have a larger effect than changes in x-y
- In x-y one can make the mesh coarser without losing out (for this particular sensor at least)
 - Having it finer does not slow down simulations however, so don't be shy about using a fine mesh

09/05/2022

Runtime stage FAQ and FEP



General questions and their answers

- "My simulation is taking too long"
 - Propagate more charges together
 - Impact? Good to make a study for your sensor type, to see impact
 - Example study on the right for ultra-thin sensor shows little impact on efficiency, but significant impact on resolution
 - Propagation time scales approximately linearly with the number of charges propagated together
 - To find which module takes a lot of time: run a few events and look at INFO output at the end
- "My RAM is filling up"
 - Propagate more charges together
 - Reduce buffer size (*buffer_per_worker*)
 - Impact? Takes longer, potentially

Max. number of charge carries propagated per step	Efficiency [%]	Resolution in x [µm]	
1	99.990 ± 0.002	2.29 ± 0.01	
5	99.988 ± 0.002	2.35 ± 0.01	
10	99.988 ± 0.002	2.44 ± 0.01	
25	99.982 ± 0.002	2.70 ± 0.01	
50	99.975 ± 0.002	3.09 ± 0.01	

Impact of number of charge carriers propagated together, for a thin MAPS with small collection electrode. See talk by Sara for study details. (Expected signal most probable value of ~800 electrons)

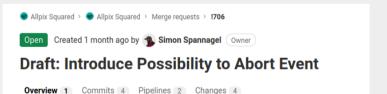
17:46:00.535	(STATUS)	Executed 8 instantiations in 33 seconds, spending 92%
of time in slow	est instan	tiation GenericPropagation:dut
17:46:00.535	(INFO)	Module GeometryBuilderGeant4 took 0.0254188 seconds
17:46:00.535	(INFO)	Module DepositionGeant4 took 2.00758 seconds
17:46:00.535	(INFO)	Module ElectricFieldReader:dut took 0.395379 seconds
17:46:00.535	(INFO)	Module DopingProfileReader:dut took 0.0382851 seconds
17:46:00.535	(INFO)	Module GenericPropagation:dut took 30.8973 seconds
17:46:00.535	(INFO)	Module PulseTransfer:dut took 0.000669902 seconds
17:46:00.535	(INFO)	Module DefaultDigitizer:dut took 0.00576612 seconds
17:46:00.535	(INFO)	Module ROOTObjectWriter took 0.111498 seconds



Simulation stuck in charge deposition stage

- Lately, simulations of multiple sensors have been known to get stuck using the [DepositionGeant4] module
- This seems to be due to a single lowenergy secondary particle created by Geant4, and is a Geant4 problem
- Possible solution: We are implementing the possibility to **abort events**
- Temporary workarounds:
 - Change the range cut
 - Try a different physics list
 - Change the random seed

15:20:03.108	(Event 13931		Polarization - z : Touchable (pointer) :	0	
15:20:03.108	(Event 13931		Touchable (pointer) :	0x7f4eb0557370	
15:20:03.108	(Event 13931				
15:20:03.108	(Event 13931		G4ParticleChange Informat	ton	
15:20:03.108	(Event 13931				
15:20:03.108	(Event 13931		# of 2ndaries :		
15:20:03.108	(Event 13931				
15:20:03.108	(Event 13931		Energy Deposit (MeV):		
15:20:03.108	(Event 13931		Non-ionizing Energy Depos	it (MeV):	
15:20:03.108	(Event 13931		Track Status :	Alive	
15:20:03.108	(Event 13931		True Path Length (mm) :	-0.00172	
15:20:03.108	(Event 13931		Stepping Control :		
15:20:03.108	(Event 13931		Mass (GeV) :	0	
15:20:03.108	(Event 13931		Charge (eplus) :		
15:20:03.108	(Event 13931		MagneticHoment : : = Position - x (mm) :	٥	
15:20:03.108	(Event 13931			0*[e hbar]/[2 m]	
15:20:03.108	(Event 13931		Position - x (mm) :	0.581	
15:20:03.108	(Event 13931		Position - y (mm) :	0.879	
15:20:03.108	(Event 13931		Position - z (mm) :		
15:20:03.108	(Event 13931		Time (ns) :		
15:20:03.109	(Event 13931		Position - x (mm) : Position - z (mm) : Time (ns) : Proper Time (ns) :		
15:20:03.109	(Event 13931		Momentum Direct - x :	0.78	
15:20:03.109	(Event 13931		Momentum Direct - y :	0.0756	
15:20:03.109	(Event 13931		Momentum Direct - z :	0.621	
15:20:03.109	(Event 13931		Kinetic Energy (MeV):	0.080135	
15:20:03.109	(Event 13931		Velocity (/c):	0.023	
15:20:03.109	(Event 13931		Polarization - x :		
15:20:03.109	(Event 13931		Polarization - y :		
15:20:03.109	(Event 13931		Polarization - z : Touchable (pointer) :		
15:20:03.109	(Event 13931		Touchable (pointer) :	0x7f4eb0557370	
15:20:03.109	(Event 13931				
15:20:03.109	(Event 13931		G4ParticleChange Informat		
15:20:03.109	(Event 13931				
15:20:03.109	(Event 13931		# of 2ndaries :		
15:20:03.109	(Event 13931				
15:20:03.109	(Event 13931		Energy Deposit (MeV):		
15:20:03.109	(Event 13931		Non-ionizing Energy Depos		
15:20:03.109	(Event 13931		Track Status :		
15:20:03.109	(Event 13931		True Path Length (mm) :	-0.00172	
15:20:03.109	(Event 13931		Stepping Control :		
15:20:03.109	(Event 13931) [Geant4]	Mass (GeV) :		
15:20:03.109	(Event 13931) [Geant4]	Charge (eplus) :	0	



Up till now, any exception e.g. thrown in Geant4 would be a ModuleError exception that ends the graceful but also more flexible, I suggest introducing a AbortEventException that stops process move on.

The effect is that no modules further down the simulation chain are called. I still have to ensure tha currently works and we don't get hickups. But since everything is parallel already TM this should be pool.

This also would allow us to define our own (per-module) criteria for aborting events, (cc)-ing @hwe



Simulation uses a lot of memory in the propagation and transfer stages

- Using [TransientPropagation] and [PulseTransfer] can lead to large amounts of RAM being used, in events with a large energy deposition
 - These events appear randomly, especially in thick sensors and low-momentum incident hadrons
 (INFO) (Event 1243) [R:DepositionGeant4] Deposited 1319918 charges in sensor of detector detectors
- Quite a recently detected issue; we're working on solutions
 - One example is dynamically changing the number of charge carriers propagated together, to reduce the impact of large events

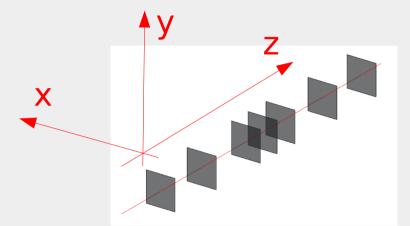


Analysis stage FAQ and FEP



Coordinate system definitions

- There is one global and one or more local coordinate systems
 - The global system holds the full setup
 - Each detector has a local system
- Detectors (and possibly passive material and sources) are placed in the global system
 - The system is right-handed and Cartesian
 - Positions relative to the origin chosen by the user
 - With zero rotation of a sensor, the z-axis is orthogonal to the sensor surface (i.e. "along the beam")
- The local systems are also right-handed and Cartesian
 - More info on next slide

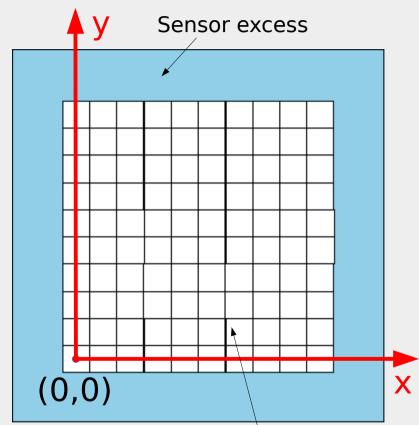


Seven sensors in the global coordinate system



Coordinate system definitions - local

- Origin at lower left of pixel grid, in the centre of pixel (0,0)
 - The pixel grid lies in the x-y plane
 - The centre is defined in **3D**, so
 z = 0 is located in the middle of the sensor thickness
- It is possible to get both local and global coordinates for most objects (e.g. MCParticles)
 - Important to keep in mind which one you are using though!



Active matrix



Frequently encountered problems

- "External analysis script doesn't work!"
 - Make sure analysis is using the same Allpix² version as the simulation run did, and include the correct libraries
- "Output files are too big!"
 - One can select what to include or exclude in [RootObjectWriter]. Including everything uses up a lot of space, and is often not necessary
 - Example: deposited and propagated charges take up a lot of space, but are only useful for post-simulation analysis in special cases
- "Efficiency is strangely low"
 - Check whether **sensor excess** is included. Important in analysis; there can be inactive silicon at the edges
 - Calculating efficiency can go wrong here, with sensor excess hits being included as hits that are expected to generate a signal
 - Hitmaps are useful for checking!
 - Check that the number of pixels assumed in analysis matches the number of pixels in the setup geometry
 - Check that the collection implant in the simulation is in the expected position
 - Output plots from [ElectricFieldReader] are useful here



General hints and tips



Figuring out what's going wrong

- Look for **warnings** and **errors** in the simulation output
 - This will indicate wrongly-configured modules, and misspelled module keywords
- Enable output plots; a lot of handy histograms are available to visualise different stages in the simulation flow
- If final results are unexpected: enable linegraphs in [GenericPropagation] to see the actual paths of the electrons and holes
 - Note: takes a long time with a fine timestep setting, so only run a few key events
- If a certain event causes issues, skip_events under [Allpix] can be used to study a certain event in detail (just make sure that the same random seed is used)



Concluding remarks

- Most problems have solutions!
 - And if not, we'll find a temporary workaround until we have a solution
- Forum is always helpful
- Developers are happy to help, and investigate and sort out any problems



Resources



Website https://cern.ch/allpix-squared



Repository https://gitlab.cern.ch/allpix-squared/allpix-squared

Mattermost channel

https://mattermost.web.cern.ch/allpix2



User Forum:

https://cern.ch/allpix-squared-forum/



Mailing Lists:

allpix-squared-users https://e-groups.cern.ch/e-groups/Egroup.do?egroupId=10262858

allpix-squared-developers https://e-groups.cern.ch/e-groups/Egroup.do?egroupId=10273730



User Manual:

https://cern.ch/allpix-squared/usermanual/allpix-manual.pdf



Backup slides



Iron-55 example source

Done as two different sources, of different intensity to match the decay probability # Let's make them point sources, for now # Source 1 # 5.9 keV, in 24.4% of decays. This is normalised to intensity 1 by default /gps/source/intensity 24.4 /gps/particle gamma /gps/pos/type Point /gps/pos/centre 0 0 -10.5 mm /gps/ene/mono 5.9 keV /gps/ang/type iso # Theta: 90 to 180 degrees is "forward", such as it is set up now /gps/ang/mintheta 150 deg /gps/ang/maxtheta 180 deg # No need to change phi, keep it isotropic there

Source 2, in the same position # 6.5 keV, in 2.85% of decays /gps/source/add 2.85 /gps/particle gamma /gps/pos/type Point /gps/pos/centre 0 0 -10.5 mm /gps/ene/mono 6.5 keV /gps/ang/type iso /gps/ang/type iso /gps/ang/mintheta 150 deg /gps/ang/maxtheta 180 deg

```
[DepositionGeant4]
physics_list = FTFP_BERT_LIV
source_type = "macro"
file_name = "./Fe55photons.mac"
max_step_length = 1.0um
number_of_particles = 1
output_plots = true
```

